



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicants: Ting-Wah Wong et al.

Serial No.: 10/081,111

Filed: February 21, 2002

For: Integrated Radio Frequency Circuits

§ Art Unit: 2811

§ Examiner: Ori Nadav

§ Atty Docket: PSS.0029P7US  
§

Commissioner for Patents  
Washington, D.C. 20231

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**REPLY TO PAPER NO. 5**

Sir:

In response to the office action mailed December 2, 2002, please amend the above-referenced patent application as follows:

**In the Claims:**

Please amend claim 1 as follows:

1. (Amended) A method comprising:  
forming a metal oxide semiconductor radio frequency circuit element over a triple  
biasing a well of said triple well through a resistor.

Please cancel claim 6 without prejudice.

Please amend claim 20 as follows:

20. (Amended) A method comprising:  
forming a first metal oxide semiconductor radio frequency circuit element over a  
triple well in a substrate;  
biasing a first well of said triple well through a first resistor with a first bias  
potential;

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Ella Sisco